

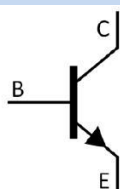
WR0<5+U, ММ Ё QSQ æ Ė ç s ll 1 Silicon NPN transistor in a TO-92(R) Plastic Package.

æ Ė ç /4 Z Ė ç /лб HG4; 35 Ы ´

High h_{FE} , 1 watts amplifier applications, complementary pair with ED1802.

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Audio frequency amplifier applications.

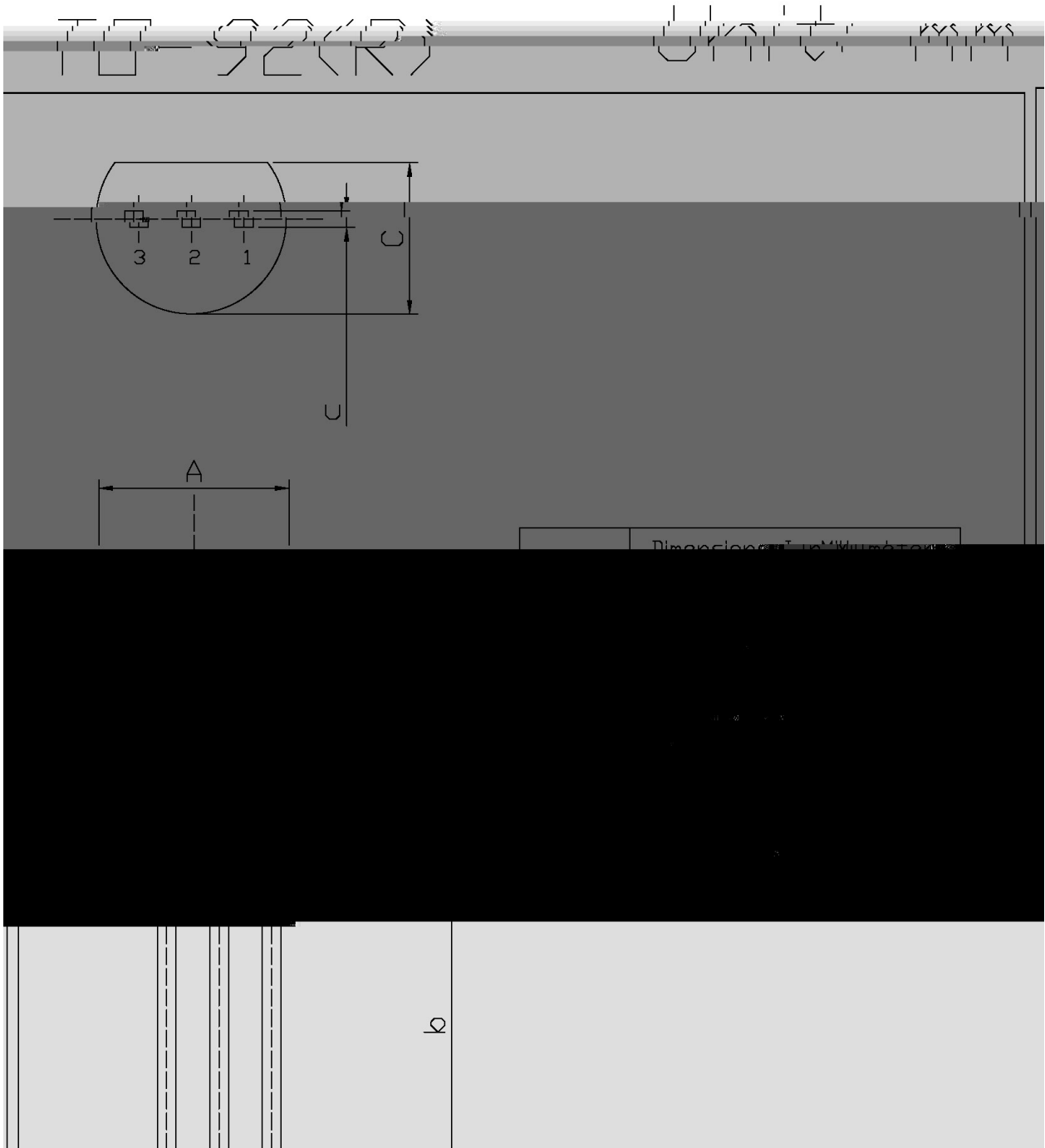


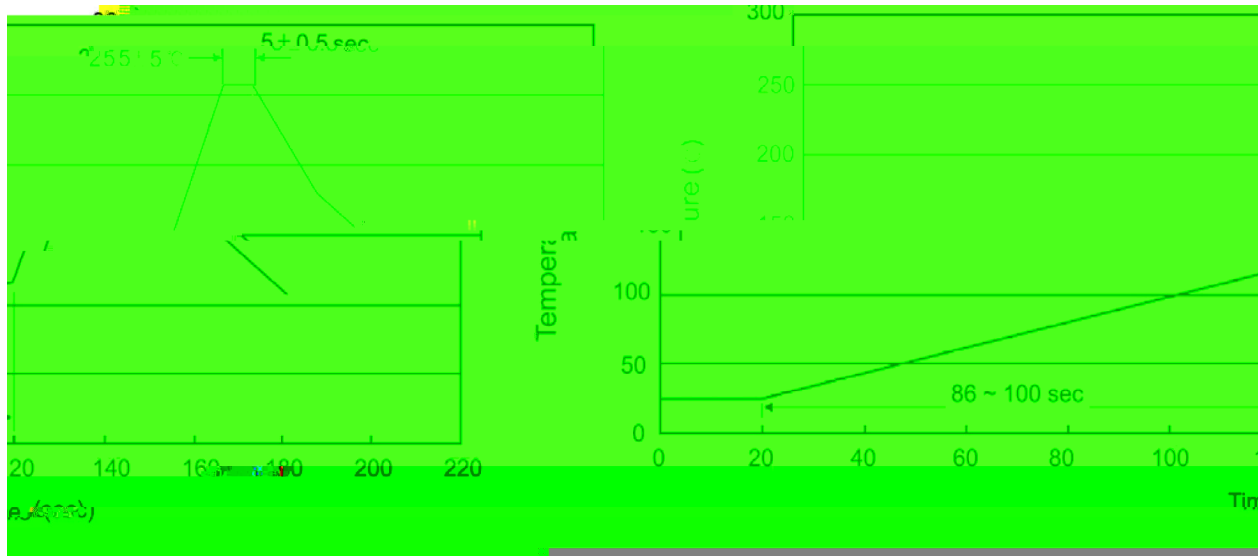
PIN1 χ Emitter

PIN 2 χ Base

PIN 3 χ Collector

h_{FE} Classifications Symbol	K	L	M	N
h_{FE} Range	106 150	132 188	170 230	213 300





б " X

1. 1. 25~150 °C, Time: 60~90sec;
2. 2. 255±5 °C, Time: 5±0.5sec;
3. 3. Cooling Speed: 2~10 °C/sec.

Note:

1. Preheating: 25~150 °C, Time: 60~90sec.
2. Peak Temp.: 255±5 °C, Duration: 5±0.5sec.
3. Cooling Speed: 2~10 °C/sec.

1. 270±5 °C, Time: 10±1 sec.

Temp.: 270±5

Time: 10±1 sec

1. BULK